TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

SF41G - SF48G

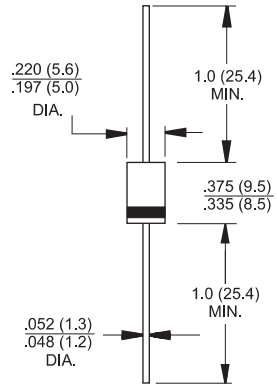
4.0 AMPS. Glass Passivated Super Fast Rectifiers

DO-201AD



Features

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inventor, free wheeling, and polarity protection application



Dimensions in inches and (millimeters)

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375",(9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 1.2 grams

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SF 41G	SF 42G	SF 43G	SF 44G	SF 45G	SF 46G	SF 47G	SF 48G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T_A = 55°C	$I_{(AV)}$	4.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	125								A
Maximum Instantaneous Forward Voltage @ 4.0A	V_F	1.0				1.3		1.7		V
Maximum DC Reverse Current @ T_A=25°C at Rated DC Blocking Voltage @ T_A=100°C	I_R	5.0 500								uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35								nS
Typical Junction Capacitance (Note 2)	Cj	100				80				pF
Thermal Resistance	$R_{\theta JA}$	25								°C/W
Operating Temperature Range	T_J	-65 to +150								°C
Storage Temperature Range	T_{STG}	-65 to +150								°C

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
3. Mount on Cu-Pad Size 16mm x 16mm on P.C.B

RATINGS AND CHARACTERISTIC CURVES (SF41G THRU SF48G)

FIG.1- MAXIMUM AVERAGE FORWARD CURRENT DERATING

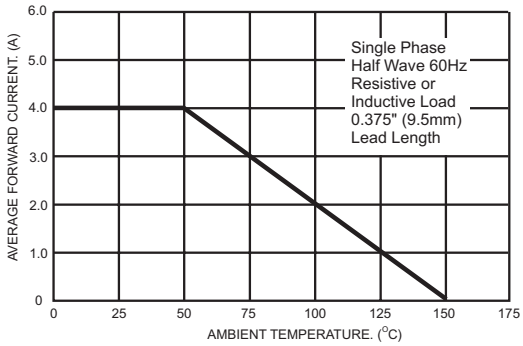


FIG.2- TYPICAL REVERSE CHARACTERISTICS

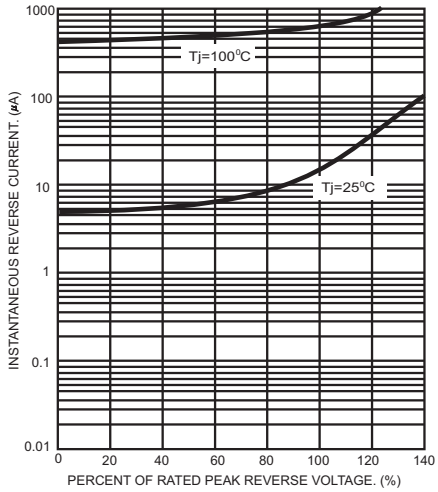


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

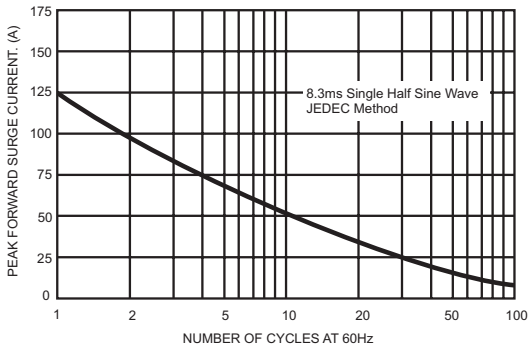


FIG.4- TYPICAL JUNCTION CAPACITANCE

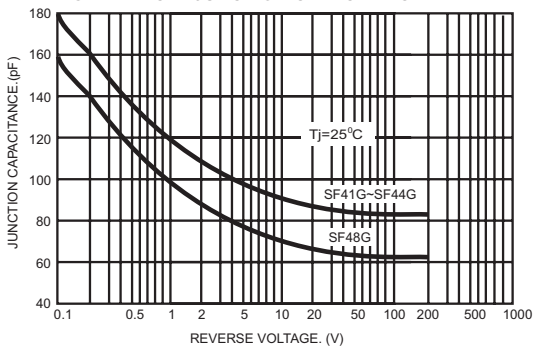


FIG.5- TYPICAL FORWARD CHARACTERISTICS

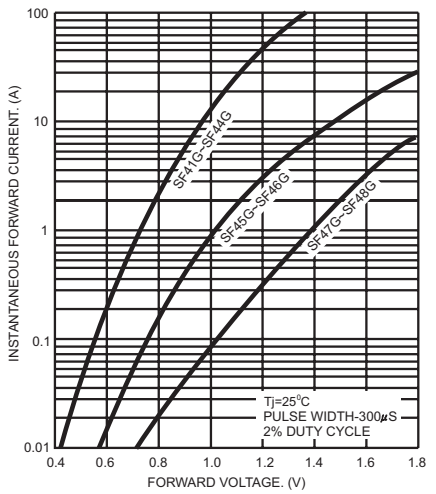


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

